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INE	ORMATION I	NICCI	ACTIDE	Application Number	09/894,125		
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STATEMENT BY APPLICANT				First Named Inventor	Shunpei YAMAZAKI et al.		
6)	(use as many sheets o	as necessa	iry)	Group Art Unit	2823		
ķ]				Examiner Name	B. Kebede		
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Examiner Initials	Cite No.1	Foreign Patent Document Kind Code ⁵ Office ³ Number ⁴ (if known)				Name of Patentee or Applicant of Cited Document	Date of Publication of Document MM-DD-YYY	R	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶		
		Office ³ Number ⁴ (if known) JP 07-130652			1		05/19/1995			AB		
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